Preferred Devices

Amplifier Transistors

NPN Silicon

• Moisture Sensitivity Level: 1

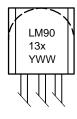
ON Semiconductor™

http://onsemi.com

COLLECTOR **EMITTER**



TO-92 CASE 29 STYLE 1



LM9013x = Specific Device Code

= G or H = Year WW = Work Week



ORDERING INFORMATION

Device	Package	Shipping
LM9013G	TO-92	5000 Units/Box
LM9013H	TO-92	5000 Units/Box

Preferred devices are recommended choices for future use and best overall value.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	25	Vdc
Collector-Base Voltage	V _{CBO}	25	Vdc
Emitter-Base Voltage	V _{EBO}	3.0	Vdc
Collector Current – Continuous	I _C	1000	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, (Note 1.) Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W

^{1.} $R_{\theta JA}$ is measured with the device soldered into a typical printed circuit board.

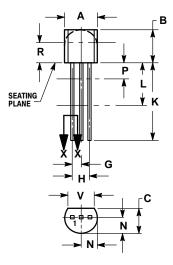
$\textbf{ELECTRICAL CHARACTERISTICS} \ (T_A = 25^{\circ}C \ unless \ otherwise \ noted)$

· · · · · · · · · · · · · · · · · · ·						
Characteristic		Symbol	Min	Max	Unit	
OFF CHARACTERISTICS						
Collector–Emitter Breakdown Voltage $(I_C = 10 \text{ mAdc}, I_B = 0)$		V _{(BR)CEO}	25	_	Vdc	
Collector–Base Breakdown Voltage ($I_C = 10 \mu Adc, I_E = 0$)		V _{(BR)CBO}	25	_	Vdc	
Emitter–Base Breakdown Voltage $(I_E = 10 \mu Adc, I_C = 0)$		V _{(BR)EBO}	3.0	_	Vdc	
Collector Cutoff Current (V _{CB} = 16 Vdc, I _E = 0)		I _{CBO}	-	0.5	μAdc	
ON CHARACTERISTICS		•				
DC Current Gain (I _C = 50 mAdc, V _{CE} = 1.0 Vdc)	LM9013G LM9013H	h _{FE}	118 144	166 202	_	
Collector–Emitter Saturation Voltage (I _C = 250 mAdc, I _B = 25 mAdc)		V _{CE(sat)}	-	1.0	Vdc	

PACKAGE DIMENSIONS

TO-92 (TO-226)

CASE 29-11 **ISSUE AL**





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
V	0.135		3.43	

- STYLE 1:
 PIN 1. EMITTER
 2. BASE
 3. COLLECTOR

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